

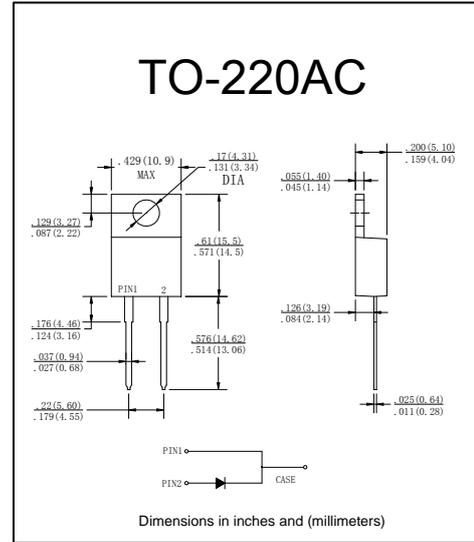


超快恢复整流二极管 Ultra-Fast Recovery Rectifier Diodes

■特征 Features

- I_o 16.0A
- V_{RRM} 200V
- 玻璃钝化芯片 Glass passivated chip
- 耐正向浪涌电流能力高
High surge forward current capability

■外形尺寸和印记 Outline Dimensions and Mark



■用途 Applications

- 快速整流用
High speed switching

■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

| 参数名称 Item | 符号 Symbol | 单位 Unit | 条件 Conditions | MUR1620 |
|---|--------------|----------------------|--|------------|
| 反向重复峰值电压 Repetitive Peak Reverse Voltage | V_{RRM} | V | | 200 |
| 平均整流输出电流 Average Rectified Output Current | I_o | A | 正弦半波 60Hz, 电阻负载, $T_c(\text{Fig.1})$ 60HZ Half-sine wave, Resistance load, $T_c(\text{Fig.1})$ | 16 |
| 正向（不重复）浪涌电流 Surge(Non-repetitive)Forward Current | I_{FSM} | A | 60Hz正弦波, 一个周期, $T_a=25^\circ\text{C}$ 60Hz sine wave, 1 cycle, $T_a=25^\circ\text{C}$ | 200 |
| 正向浪涌电流的平方对电流浪涌持续时间的积分值 Current Squared Time | I^2t | A^2s | $1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$ | 167 |
| 贮存温度 Storage Temperature | T_{stg} | $^\circ\text{C}$ | | -55 ~ +150 |
| 结温 Junction Temperature | T_j | $^\circ\text{C}$ | | -55 ~ +175 |

■电特性 ($T_a=25^\circ\text{C}$ 除非另有规定)

Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

| 参数名称 Item | 符号 Symbol | 单位 Unit | 测试条件 Test Condition | 最大值 Max | |
|---------------------------------|------------------|--------------------|---|-------------------------|-----|
| 正向峰值电压 Peak Forward Voltage | V_{FM} | V | $I_{FM}=16.0\text{A}$ | 0.975 | |
| 反向峰值电流 Peak Reverse Current | I_{RRM1} | μA | $V_{RM}=V_{RRM}$ | $T_a=25^\circ\text{C}$ | 10 |
| | I_{RRM2} | | | $T_a=125^\circ\text{C}$ | 500 |
| 反向恢复时间 Reverse Recovery Time | T_{rr} | ns | $I_F=0.5\text{A}$ $I_{RM}=1\text{A}$ $I_{RR}=0.25\text{A}$ | 50 | |
| 热阻 Thermal Resistance | $R_{\theta J-C}$ | $^\circ\text{C/W}$ | 结和壳之间 Between junction and case | 2.0 | |

■特性曲线（典型） Characteristics(Typical)

图1: 正向电流降额曲线
FIG1: IF (AV) --Tc Derating

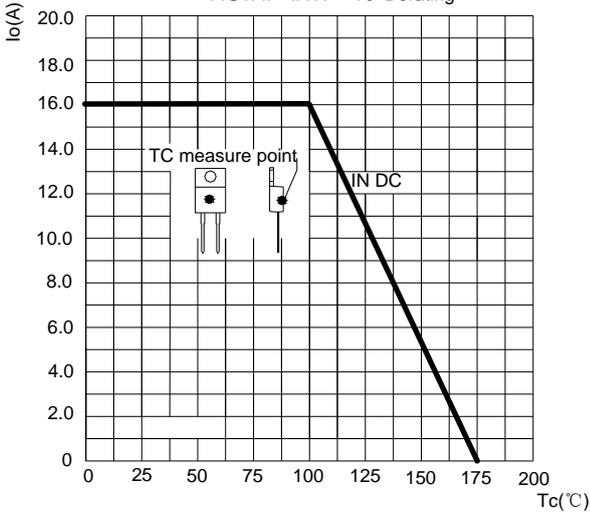


图2: 耐正向浪涌电流曲线
FIG2: Surge Forward Current Capacity

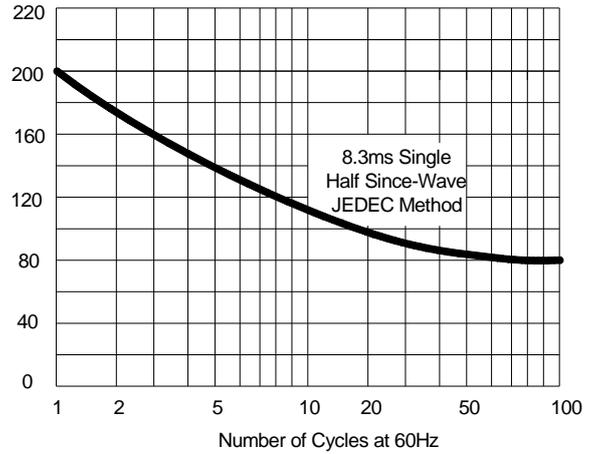


图3: 正向电压曲线
FIG3: Instantaneous Forward Voltage

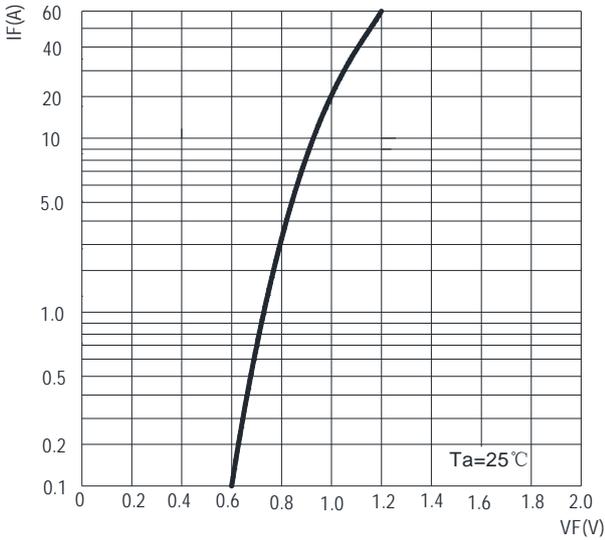


图4: 反向电流曲线
FIG4: Typical Reverse Characteristics

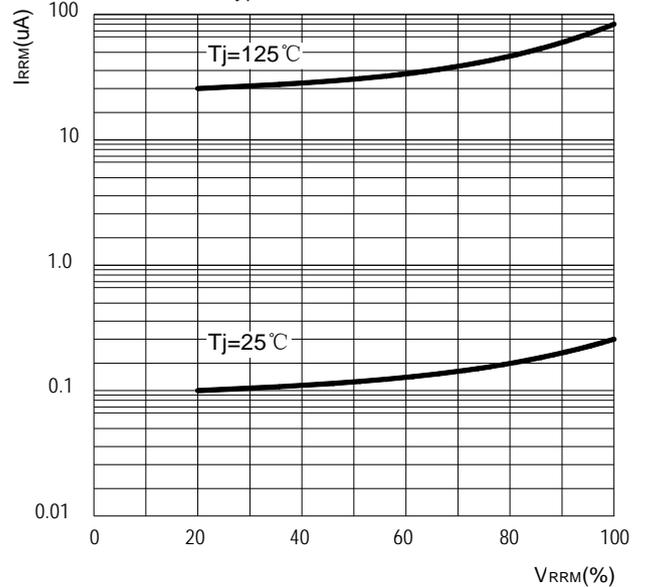
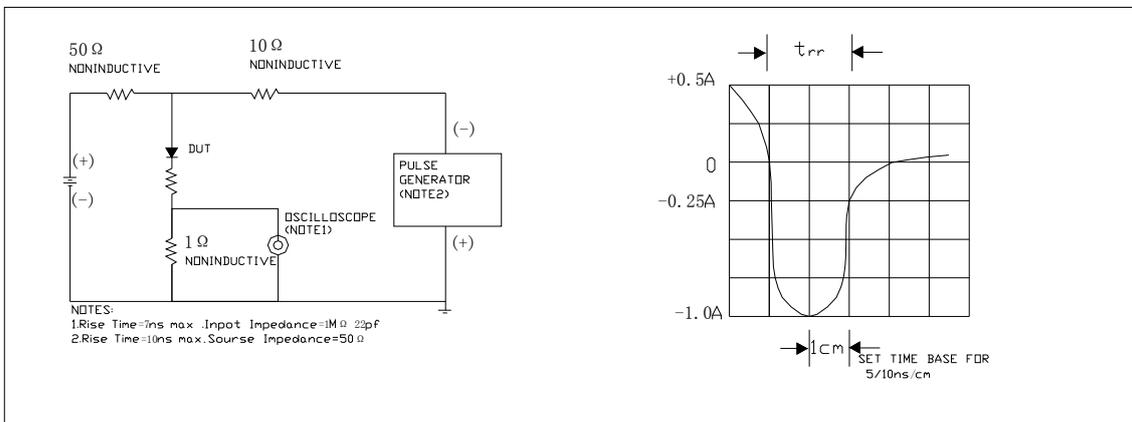


图5: 反向恢复时间试验电路及测试波形示意图
Diagram of circuit and Testing wave form of reverse recovery time



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